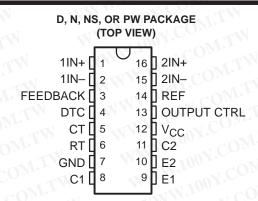
- Complete PWM Power Control Circuitry
- Uncommitted Outputs for 200-mA Sink or Source Current
- Output Control Selects Single-Ended or Push-Pull Operation
- Internal Circuitry Prohibits Double Pulse at Either Output
- Variable Dead Time Provides Control Over Total Range
- Internal Regulator Provides a Stable 5-V Reference Supply With 5% Tolerance
- Circuit Architecture Allows Easy Synchronization



description

The TL494 incorporates all the functions required in the construction of a pulse-width-modulation (PWM) control circuit on a single chip. Designed primarily for power-supply control, this device offers the flexibility to tailor the power-supply control circuitry to a specific application.

The TL494 contains two error amplifiers, an on-chip adjustable oscillator, a dead-time control (DTC) comparator, a pulse-steering control flip-flop, a 5-V, 5%-precision regulator, and output-control circuits.

The error amplifiers exhibit a common-mode voltage range from -0.3 V to $V_{CC}-2$ V. The dead-time control comparator has a fixed offset that provides approximately 5% dead time. The on-chip oscillator can be bypassed by terminating RT to the reference output and providing a sawtooth input to CT, or it can drive the common circuits in synchronous multiple-rail power supplies.

The uncommitted output transistors provide either common-emitter or emitter-follower output capability. The TL494 provides for push-pull or single-ended output operation, which can be selected through the output-control function. The architecture of this device prohibits the possibility of either output being pulsed twice during push-pull operation.

The TL494C is characterized for operation from 0°C to 70°C. The TL494I is characterized for operation from –40°C to 85°C.

FUNCTION TABLE

INPUT TO OUTPUT CTRL	OUTPUT FUNCTION
V _I = GND	Single-ended or parallel output
$V_I = V_{ref}$	Normal push-pull operation

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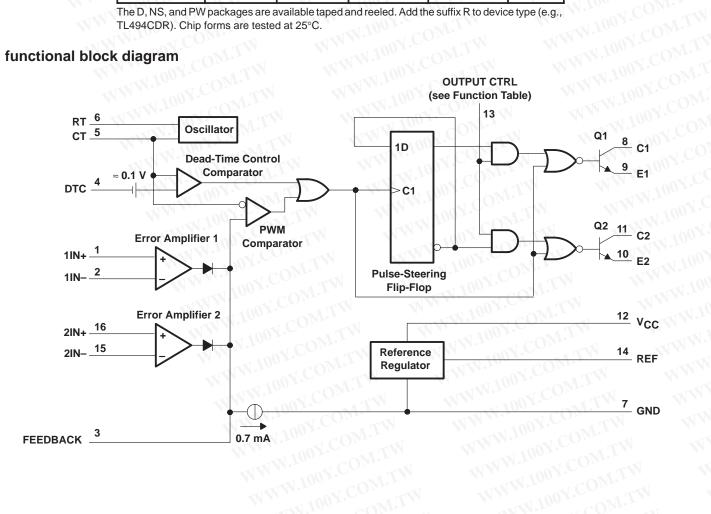
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AVAILABLE OPTIONS

TW	W	AVAILABLE	OPTIONS	W.	11
COM	1/1	PACKAG	ED DEVICES	N V	M. A.
Y.COM.T	SMALL OUTLINE (D)	PLASTIC DIP (N)	SMALL OUTLINE (NS)	SHRINK SMALL OUTLINE (PW)	CHIP FORM (Y)
0°C to 70°C	TL494CD	TL494CN	TL494CNS	TL494CPW	TL494Y
-40°C to 85°C	TL494ID	TL494IN	CO.	- TV I	41

The D, NS, and PW packages are available taped and reeled. Add the suffix R to device type (e.g., TL494CDR). Chip forms are tested at 25°C.

functional block diagram



TL494 PULSE-WIDTH-MODULATION CONTROL CIRCUITS

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

WWW. 100X.CO. TITW WWW. TI 100X.CO.	II. M. 100 I	TL494	UNIT
Supply voltage, V _{CC} (see Note 1)	WW 100	41	V
Amplifier input voltage, V _I		V _{CC} +0.3	V
Collector output voltage, VO		(41)	V
Collector output current, IO			mA
MMM. JON. CO. TM MMM. JOON	D package	73	TI
Dealings (Married in readings 0 - (see Nation 2 and 2)	N package	88	°C
Package thermal impedance, θJA (see Notes 2 and 3)	NS package	64	DV.C.
	PW package	108	Mo
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	D, N, or PW package	260	°C
Storage temperature range, T _{Sto}	V.COM TIN	-65 to 150	∘c

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to the network ground terminal.
 - 2. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can impact reliability.
 - 3. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

recommended operating conditions

TANN TOO TO COMP.	1	TL494		
	MI	N MAX	UNIT	
Supply voltage, V _{CC}	OM.T.	7 40	V	
Amplifier input voltage, V _I	-0.	3 V _{CC} -2	V	
Collector output voltage, VO	COM	40	V	
Collector output current (each transistor)	COM	200	mA	
Current into feedback terminal	COMIT	0.3	mA	
Oscillator frequency, fosc	Y.O.	1 300	kHz	
Timing capacitor, C _T	0.4	7 10000	nF	
Timing resistor, R _T	ON1.	8 500	kΩ	
Operating free six temperature T	94C	0 70	°C	
Operating free-air temperature, T _A	941 –4	0 85] "	

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electrical characteristics over recommended operating free-air temperature range, $V_{CC} = 15 \text{ V}$, f = 10 kHz (unless otherwise noted)

reference section

TIMN TO COMP.	MM. T. COM	TL4	1		
PARAMETER	TEST CONDITIONS†	MIN	TYP [‡]	MAX	UNIT
Output voltage (REF)	I _O = 1 mA	4.75	5	5.25	V
Input regulation	V _{CC} = 7 V to 40 V		2	25	mV
Output regulation	I _O = 1 mA to 10 mA	V	1	15	mV
Output voltage change with temperature	$\Delta T_A = MIN \text{ to MAX}$	4	2	10	mV/V
Short-circuit output current§	REF = 0 V		25	N'Inc	mA

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

oscillator section, C_T = 0.01 μ F, R_T = 12 $k\Omega$ (see Figure 1)

PARAMETER	IN WALLSON	TL494, TL494I			1.100_{J}
	TEST CONDITIONS†	MIN	TYP‡	MAX	UNIT
Frequency	M. TOWN. TOWN. COM	TW	10	WW	kHz
Standard deviation of frequency¶	All values of V _{CC} , CT, RT, and T _A constant		100		Hz/kHz
Frequency change with voltage	$V_{CC} = 7 \text{ V to } 40 \text{ V}, \qquad T_{A} = 25^{\circ}\text{C}$	1.7	1	44	Hz/kHz
Frequency change with temperature#	$\Delta T_A = MIN \text{ to MAX}$	TIT	N	10	Hz/kHz

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

$$\sigma \ = \ \sqrt{\frac{\sum\limits_{n=1}^{N} \ (x_n - \overline{X})^2}{N-1}}$$

error-amplifier section (see Figure 2)

MM, 100Xin TAN MM		OTL4			
TEST COND	ITIONS	MIN	TYP [‡]	MAX	UNIT
V _O (FEEDBACK) = 2.5 V	WW.	1.10	(C2)	10	mV
V _O (FEEDBACK) = 2.5 V	William	W.100	25	250	nA
V _O (FEEDBACK) = 2.5 V	M.TW WY	10°	0.2	1	μΑ
V _{CC} = 7 V to 40 V	OM.TW W	-0.3 to V _{CC} -2	00Y.C	MO	V
$\Delta V_{O} = 3 \text{ V}, \qquad R_{L} = 2 \text{ k}\Omega,$	$V_0 = 0.5 \text{ V to } 3.5 \text{ V}$	70	95	CON	dB
$V_O = 0.5 \text{ V to } 3.5 \text{ V},$	$R_L = 2 k\Omega$	MAA	800		kHz
$\Delta V_O = 40 \text{ V}, \qquad T_A = 25^{\circ}\text{C}$	V.COM	65	80	V.CO	dB
$V_{ID} = -15 \text{ mV to } -5 \text{ V},$	V (FEEDBACK) = 0.7 V	0.3	0.7		mA
V _{ID} = 15 mV to 5 V,	V (FEEDBACK) = 3.5 V	-2			mA
	$\begin{split} & \text{V}_{\text{O}} \text{ (FEEDBACK)} = 2.5 \text{ V} \\ & \text{V}_{\text{O}} \text{ (FEEDBACK)} = 2.5 \text{ V} \\ & \text{V}_{\text{O}} \text{ (FEEDBACK)} = 2.5 \text{ V} \\ & \text{V}_{\text{CC}} = 7 \text{ V to } 40 \text{ V} \\ & \Delta \text{V}_{\text{O}} = 3 \text{ V}, \qquad \text{R}_{\text{L}} = 2 \text{ k}\Omega, \\ & \text{V}_{\text{O}} = 0.5 \text{ V to } 3.5 \text{ V}, \\ & \Delta \text{V}_{\text{O}} = 40 \text{ V}, \qquad \text{T}_{\text{A}} = 25^{\circ}\text{C} \\ & \text{V}_{\text{ID}} = -15 \text{ mV to } -5 \text{ V}, \end{split}$	$\begin{array}{c} \text{V}_{O} \text{ (FEEDBACK)} = 2.5 \text{ V} \\ \text{V}_{O} \text{ (FEEDBACK)} = 2.5 \text{ V} \\ \\ \text{V}_{CC} = 7 \text{ V to } 40 \text{ V} \\ \\ \Delta \text{V}_{O} = 3 \text{ V}, \qquad \text{R}_{L} = 2 \text{ k}\Omega, \qquad \text{V}_{O} = 0.5 \text{ V to } 3.5 \text{ V} \\ \\ \text{V}_{O} = 0.5 \text{ V to } 3.5 \text{ V}, \qquad \text{R}_{L} = 2 \text{ k}\Omega \\ \\ \Delta \text{V}_{O} = 40 \text{ V}, \qquad \text{T}_{A} = 25^{\circ}\text{C} \\ \\ \text{V}_{ID} = -15 \text{ mV to } -5 \text{ V}, \qquad \text{V (FEEDBACK)} = 0.7 \text{ V} \end{array}$	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$

 $[\]ddagger$ All typical values, except for parameter changes with temperature, are at T_A = 25°C.



[‡] All typical values, except for parameter changes with temperature, are at $T_A = 25$ °C.

[§] Duration of the short circuit should not exceed one second.

 $[\]ddagger$ All typical values, except for parameter changes with temperature, are at T_A = 25°C.

[¶] Standard deviation is a measure of the statistical distribution about the mean as derived from the formula:

[#] Temperature coefficient of timing capacitor and timing resistor are not taken into account.

electrical characteristics over recommended operating free-air temperature range, V_{CC} = 15 V, f = 10 kHz, T_A = 25°C (unless otherwise noted)

reference section

MAN COMP.	0V.101 W	TL494Y	UNIT
PARAMETER	TEST CONDITIONS [†]	MIN TYPT MAX	
Output voltage (REF)	I _O = 1 mA	5 (0)	٧
Input regulation	V _{CC} = 7 V to 40 V	2	mV
Output regulation	I _O = 1 mA to 10 mA	101.00	mV
Short-circuit output current [‡]	REF = 0 V	25	mA

 $[\]dagger$ All typical values, except for parameter changes with temperature, are at $T_A = 25$ °C.

oscillator section, C_T = 0.01 μ F, R_T = 12 $k\Omega$ (see Figure 1)

N MAN, ON CO. LAN	TL494Y			V.Co.
TEST CONDITIONS!	MIN	TYP [†]	MAX	UNIT
M. TAN. TOO.	1	10	W.Iu	kHz
All values of V _{CC} , CT, RT, and T _A constant		100	-TXN.1	Hz/kHz
V _{CC} = 7 V to 40 V		1	WY T	Hz/kHz
vith temperature, are at T _A = 25°C.	a:	V	NWN	1.10
	$V_{CC} = 7 \text{ V to } 40 \text{ V}$ with temperature, are at $T_A = 25^{\circ}\text{C}$.	All values of V _{CC} , CT, RT, and T _A constant $V_{CC} = 7 \text{ V to } 40 \text{ V}$	TEST CONDITIONS MIN TYPT 10 All values of V_{CC} , CT, RT, and T_A constant $V_{CC} = 7 \text{ V to } 40 \text{ V}$ 11 with temperature, are at $T_A = 25^{\circ}\text{C}$.	TEST CONDITIONS† MIN TYP† MAX 10 All values of V_{CC} , CT, RT, and T_A constant $V_{CC} = 7 \text{ V to } 40 \text{ V}$ vith temperature, are at $T_A = 25^{\circ}\text{C}$.

[†] All typical values, except for parameter changes with temperature, are at T_A = 25°C.

$$\sigma = \sqrt{\frac{\sum_{n=1}^{N} (x_n - \overline{X})^2}{N-1}}$$

WY	N. COM		TI	TL494Y		1111
PARAMETER	TEST CONDI	MIN	TYP [†]	MAX	UNIT	
Input offset voltage	V _O (FEEDBACK) = 2.5 V	INW.100	COM	2		mV
Input offset current	V _O (FEEDBACK) = 2.5 V	W 1001	· CON	25		nA
Input bias current	V _O (FEEDBACK) = 2.5 V	11/1/	1.00	0.2		μΑ
Open-loop voltage amplification	$\Delta V_{O} = 3 \text{ V}, \qquad R_{L} = 2 \text{ k}\Omega,$	V _O = 0.5 V to 3.5 V	ov.Co	95	N	dB
Unity-gain bandwidth	V _O = 0.5 V to 3.5 V,	$R_L = 2 k\Omega$	T C	800	×XI	kHz
Common-mode rejection ratio	$\Delta V_{O} = 40 \text{ V}$	W. W.	60 2.	80	. "	dB
Output sink current (FEEDBACK)	$V_{ID} = -15 \text{ mV to } -5 \text{ V},$	V (FEEDBACK) = 0.7 V	1001.	0.7	IN	mA

[†] All typical values, except for parameter changes with temperature, are at $T_A = 25$ °C. WWW.100Y.COM

[‡] Duration of the short circuit should not exceed one second.

[§] Standard deviation is a measure of the statistical distribution about the mean as derived from the formula:

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electrical characteristics over recommended operating free-air temperature range, V_{CC} = 15 V, f = 10 kHz (unless otherwise noted)

output section COM

TANN TO COM		WW. Tay Com		TL4	TL494, TL494Y		<u>.</u>
PARAMETER		TEST CON	DITIONS	MIN	TYP†	MAX	UNIT μA μA V mA
Collector off-state current	MITW	V _{CE} = 40 V,	V _{CC} = 40 V		2	100	μΑ
Emitter off-state current	WILL	$V_{CC} = V_{C} = 40 \text{ V},$	V _E = 0	1/1	XXI	-100	μΑ
Collector-emitter saturation voltage	Common emitter	V _E = 0,	I _C = 200 mA	V	1.1	1.3	Von
	Emitter follower	$V_{O(C1 \text{ or } C2)} = 15 \text{ V},$	$I_E = -200 \text{ mA}$		1.5	2.5	
Output control input current	1 11.11	$V_I = V_{ref}$	O.M. I			3.5	mA

 $[\]dagger$ All typical values except for temperature coefficient are at T_A = 25°C.

dead-time control section (see Figure 1)

PARAMETER	TO THE TOTAL OF TH	TL49	1007		
	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input bias current (DEAD-TIME CTRL)	V _I = 0 to 5.25 V	-31	-2	-10	μА
Maximum duty cycle, each output	V_I (DEAD-TIME CTRL) = 0, C_T = 0.1 μF, R_T = 12 k Ω	1	45%	- TV	W.100
land three hold waters (DEAD TIME CTDL)	Zero duty cycle	TW	3	3.3	V/10
Input threshold voltage (DEAD-TIME CTRL)	Maximum duty cycle	0		W	V

[†] All typical values except for temperature coefficient are at $T_A = 25$ °C.

PWM comparator section (see Figure 1)

PARAMETER	4 100 1	TL494, TL494Y			IV
	TEST CONDITIONS	MIN	TYP [†]	MAX	UNIT
Input threshold voltage (FEEDBACK)	Zero duty cycle	N. Co.	4	4.5	V
Input sink current (FEEDBACK)	V (FEEDBACK) = 0.7 V	0.3	0.7		mA

[†] All typical values except for temperature coefficient are at $T_A = 25$ °C.

total device

PARAMETER TEST	MM. 1000:0 20 LM M. 201		TL494, TL494Y		
	TEST CONDITIONS	ONDITIONS		MAX	UNIT
Ota a alla coma de coma at	DT V . All other invited and extracted	V _{CC} = 15 V	6	10	Л
Standby supply current $RT = V_{ref}$, All other inputs and outputs open	V _{CC} = 40 V	9	15	mA	
Average supply current	V _I (DEAD-TIME CTRL) = 2 V,	See Figure 1	7.5	$M_{i,I}$	mA

[†] All typical values except for temperature coefficient are at $T_A = 25$ °C.

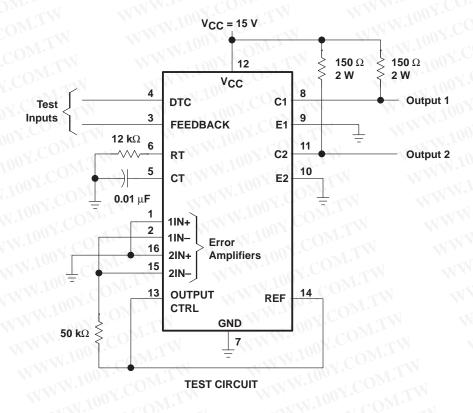
switching characteristics, $T_A = 25^{\circ}C$

	M. 1003. "ODI'I.		TL494, TL494Y			
PARAMETER	TEST CONDITION	MIN T	YP†	MAX	UNIT	
Rise time	Common-emitter configuration,	See Figure 3	MW	100	200	ns
Fall time				25	100	ns
Rise time	Emitter-follower configuration, See F	Can Figure 4	4.	100	200	ns
Fall time		See Figure 4		40	100	ns
Fall time All typical values except for temperature co	W 1001.	See Figure 4		40	100	_

[†] All typical values except for temperature coefficient are at $T_A = 25$ °C.



PARAMETER MEASUREMENT INFORMATION



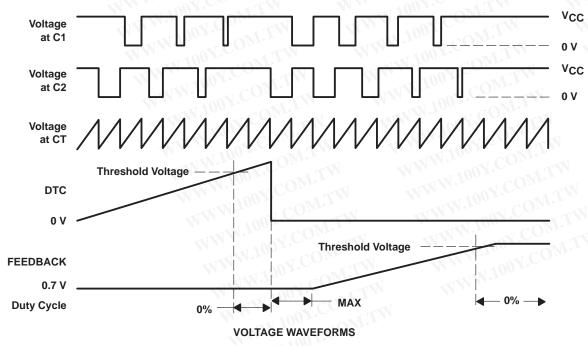


Figure 1. Operational Test Circuit and Waveforms

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PARAMETER MEASUREMENT INFORMATION

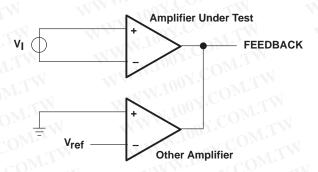
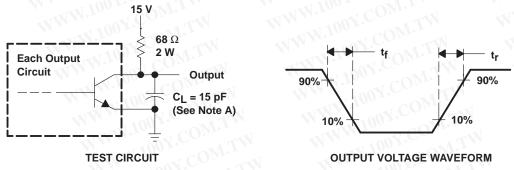
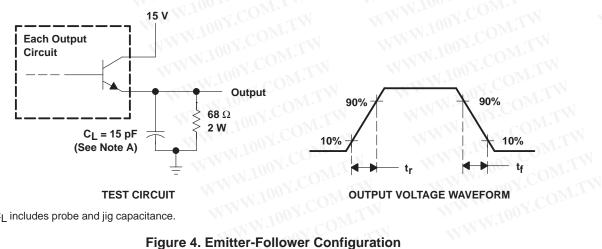


Figure 2. Amplifier Characteristics



NOTE A: C_L includes probe and jig capacitance.

Figure 3. Common-Emitter Configuration



NOTE A: C_L includes probe and jig capacitance.

Figure 4. Emitter-Follower Configuration

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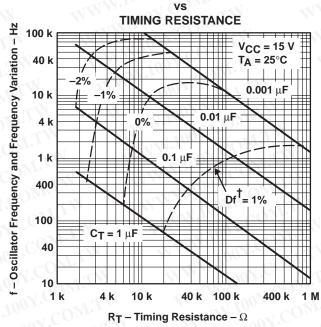


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TYPICAL CHARACTERISTICS

OSCILLATOR FREQUENCY AND FREQUENCY VARIATION†



[†] Frequency variation (Δf) is the change in oscillator frequency that occurs over the full temperature range.

Figure 5

AMPLIFIER VOLTAGE AMPLIFICATION FREQUENCY 100 V_{CC} = 15 V 90 $\Delta V_0 = 3 V$ A - Amplifier Voltage Amplification - dB T_A = 25°C 80 70 60 50 40 30 20 10 0 10 100 10 k 1 M 1 k 100 k f - Frequency - Hz Figure 6

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